

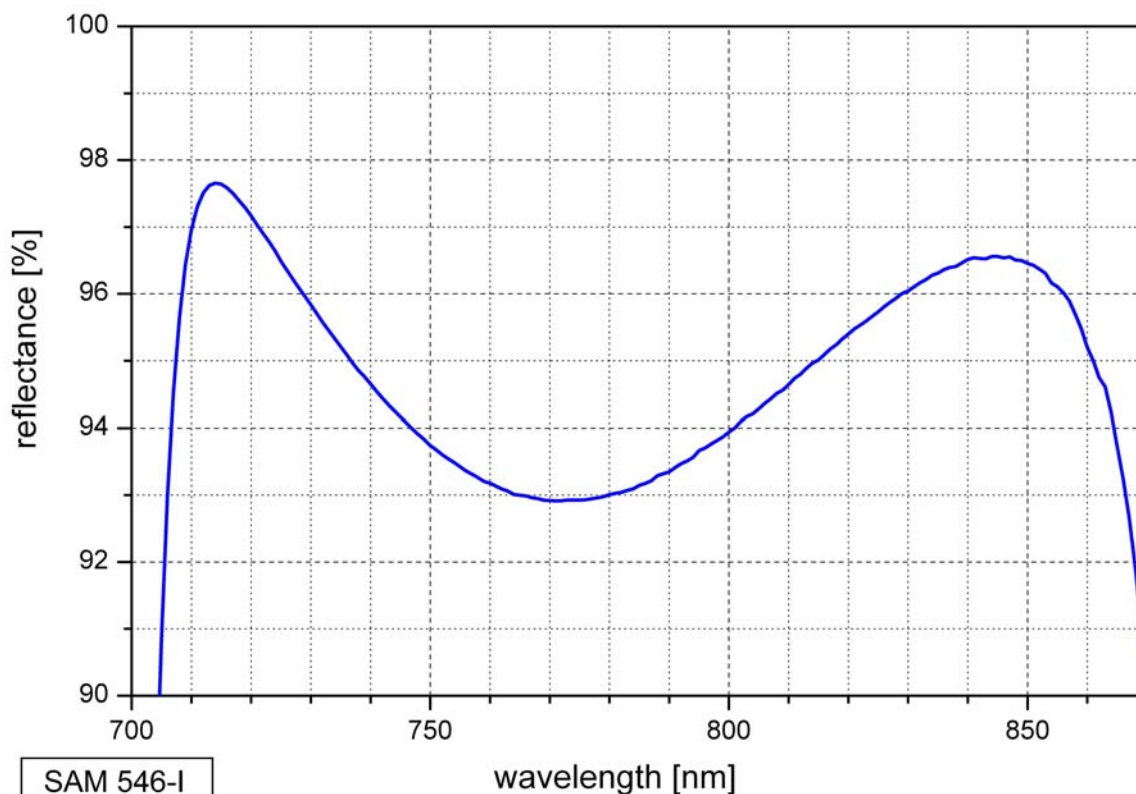
SAM™ data sheet SAM-800-6-x-500fs, $\lambda = 800$ nm

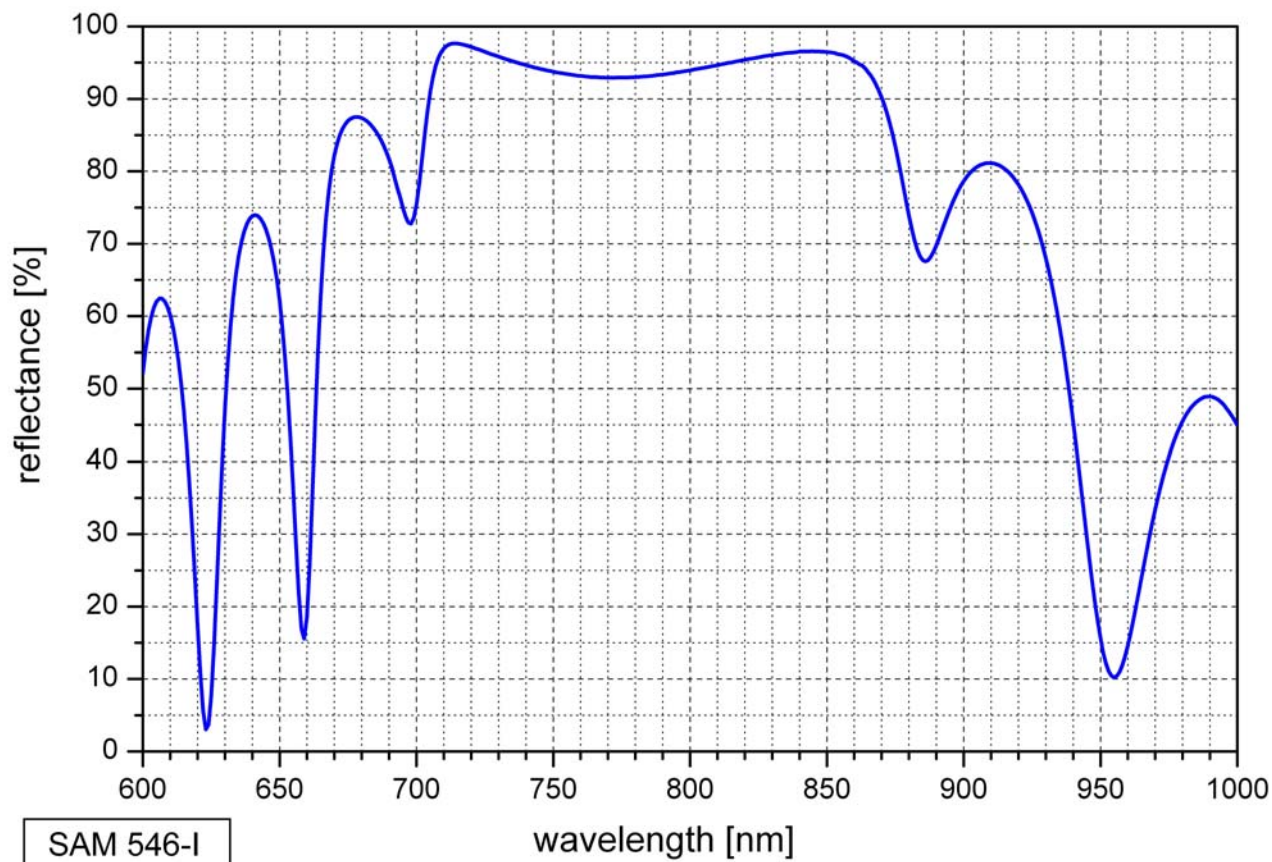
Laser wavelength	$\lambda = 800$ nm
High reflection band (R > 93%)	$\lambda = 710 .. 850$ nm
Absorbance	$A_0 = 6$ %
Modulation depth	$\Delta R = 2$ %
Non-saturable loss	$A_{ns} = 4$ %
Saturation fluence	$\Phi_{sat} = 50$ $\mu\text{J}/\text{cm}^2$
Relaxation time constant	$\tau \sim 500$ fs
Damage threshold	600 MW/cm ²
Chip area	4mm x 4mm; other dimensions on request
Chip thickness	400 μm
Protection	the SAM is protected with a dielectric front layer

Mounting of SAM-800-6-x-500fs denotes the type of mounting as follows:

x = 0	unmounted
x = 12.7 g	glued on a gold plated Cu-cylinder with 12.7 mm \varnothing
x = 25.4 g	glued on a gold plated Cu-cylinder with 25.4 mm \varnothing
x = 12.7 s	soldered on a gold plated Cu-cylinder with 12.7 mm \varnothing
x = 25.4 s	soldered on a gold plated Cu-cylinder with 25.4 mm \varnothing
x = 25.0 w	soldered on a water cooled Cu-cylinder with 25.0 mm \varnothing
x = FC	mounted on a 1 m monomode fiber cable with FC connector

Low intensity spectral reflectance





SAM 546-I

wavelength [nm]